

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	5	l1 and (spacer near10 (sin or (silicon adj nitride)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:02
L3	185	(spacer near10 (sin or (silicon adj nitride))) and (charge near trapping)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:03
L4	85	(spacer near10 (sin or (silicon adj nitride))) and (charge near trapping) and (ldd or (lightly adj doped))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:03
L5	11	(spacer near10 (sin or (silicon adj nitride))).clm. and (charge near trapping) and (ldd or (lightly adj doped))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:03
L6	5	(spacer near10 (sin or (silicon adj nitride))).clm. and (charge near trapping).clm. and (ldd or (lightly adj doped))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:03
L7	2	(spacer near10 (sin or (silicon adj nitride))).clm. and (charge near trapping).clm. and (ldd or (lightly adj doped)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:04
L8	2	(spacer near10 (sin or (silicon adj nitride))).clm. and (charge near (trap or trapping)).clm. and (ldd or (lightly adj doped)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:04
L9	2	(spacer near10 (sin or (silicon adj nitride))).clm. and (charge near5 (trap or trapping)).clm. and (ldd or (lightly adj doped)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:04
L10	4	(spacer near10 (sin or (silicon adj nitride))).clm. and (charge near5 (trap or trapping or storage)).clm. and (ldd or (lightly adj doped)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:05

L11	6	(spacer near10 (sin or (silicon adj nitride))) .clm. and (charge).clm. and (ldd or (lightly adj doped)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:05
L12	1	(spacer near10 (sin or (silicon adj nitride))) .clm. and (charge).clm. and (ldd or (lightly adj doped)).clm. and nonvolatile	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:05
L13	7	(spacer near10 (sin or (silicon adj nitride))) and (charge).clm. and (ldd or (lightly adj doped)).clm. and nonvolatile	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:05
L14	21	(spacer near10 (sin or (silicon adj nitride))) and (charge) and (ldd or (lightly adj doped)).clm. and nonvolatile	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:06
L15	97	(spacer near10 (sin or (silicon adj nitride))) and (charge) and (ldd or (lightly adj doped)) and nonvolatile	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:06
L16	48	(spacer near10 (sin or (silicon adj nitride))) and (charge) and (ldd or (lightly adj doped)) and nonvolatile .clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:06
L17	22	(spacer near10 (sin or (silicon adj nitride))) and (charge).clm. and (ldd or (lightly adj doped)) and nonvolatile .clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 18:06